

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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1500 Watt Peak Power Mosorb™ Zener Transient Voltage Suppressors

Unidirectional*

Mosorb devices are designed to protect voltage sensitive components from high voltage, high-energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. These devices are ON Semiconductor's exclusive, cost-effective, highly reliable Surmetic™ axial leaded package and are ideally-suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications, to protect CMOS, MOS and Bipolar integrated circuits.

Specification Features

- Working Peak Reverse Voltage Range 5.0 V to 45 V
- Peak Power 1500 Watts @ 1 ms
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 5 μA Above 10 V
- Response Time is Typically < 1 ns
- Pb-Free Packages are Available*

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic

FINISH: All external surfaces are corrosion resistant and leads are

readily solderable

MAXIMUM LEAD TEMPERATURE FOR SOLDERING PURPOSES:

260°C, 1/16" from the case for 10 seconds

POLARITY: Cathode indicated by polarity band

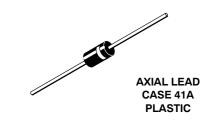
MOUNTING POSITION: Any



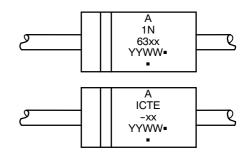
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAMS



A = Assembly Location 1N63xx = JEDEC Device Code ICTE-xx = ON Device Code

YY = Year WW = Work Week ■ Pb-Free Package (Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
1N63xx, G	Axial Lead (Pb-Free)	500 Units/Box
1N63xxRL4, G	Axial Lead (Pb-Free)	1500/Tape & Reel
ICTE-xx, G	Axial Lead (Pb-Free)	500 Units/Box
ICTE-xxRL4, G	Axial Lead (Pb-Free)	1500/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T _L ≤ 25°C	P _{PK}	1500	W
Steady State Power Dissipation @ $T_L \le 75^{\circ}C$, Lead Length = $3/8''$ Derated above $T_L = 75^{\circ}C$	P _D	5.0 20	W mW/°C
Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	20	°C/W
Forward Surge Current (Note 2) @ T _A = 25°C	I _{FSM}	200	Α
Operating and Storage Temperature Range	T _J , T _{stg}	- 65 to +175	°C

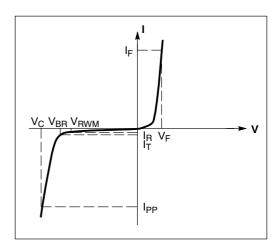
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Nonrepetitive current pulse per Figure 5 and derated above T_A = 25°C per Figure 2.
- 2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless

otherwise noted, V_F = 3.5 V Max. @ I_F (Note 3) = 100 A)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I _T
I _T	Test Current
ΘV _{BR}	Maximum Temperature Variation of V _{BR}
I _F	Forward Current
V _F	Forward Voltage @ I _F



Uni-Directional TVS

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted, $V_F = 3.5$ V Max. @ I_F (Note 3) = 100 A)

		V _{RWM}	I _R @	Breakdown Voltage			V _C @ I _{PP} (Note 6)		V _C (Volts) (Note 6)			
JEDEC Device [†] Device		(Note 4) V _{RWM}		V _{BR} (Note 5) (Volts) @ I _T		@ I _T	V _C	I _{PP}	@ l _{PP} =	@ l _{pp} =	ΘV_{BR}	
(ON Device)	Marking	(Volts)	(μΑ)	Min	Nom	Max	(mA)	(Volts)	(A)	1 A	10 A	(mV/°C)
1N6373, G	1N6373	5.0	300	6.0	-	-	1.0	9.4	160	7.1	7.5	4.0
1N6374, G	1N6374	8.0	25	9.4	-	-	1.0	15	100	11.3	11.5	8.0
1N6375, G	1N6375	10	2.0	11.7	-	-	1.0	16.7	90	13.7	14.1	12
1N6376, G	1N6376	12	2.0	14.1	-	-	1.0	21.2	70	16.1	16.5	14
1N6377, G	1N6377	15	2.0	17.6	-	-	1.0	25	60	20.1	20.6	18
1N6380, G	1N6380	36	2.0	42.4	-	-	1.0	65.2	23	50.6	54.3	50
1N6381, G	1N6381	45	2.0	52.9	-	-	1.0	78.9	19	63.3	70	60
ICTE-5RLG	ICTE-5	5.0	300	6.0	-	-	1.0	9.4	160	7.1	7.5	4.0
ICTE-10RLG	ICTE-10	10	2.0	11.7	-	_	1.0	16.7	90	13.7	14.1	8.0
ICTE-12RLG	ICTE-12	12	2.0	14.1	-	-	1.0	21.2	70	16.1	16.5	12
ICTE-15RLG	ICTE-15	15	2.0	17.6	-	-	1.0	25	60	20.1	20.6	14
ICTE-18, G	ICTE-18	18	2.0	21.2	-	_	1.0	30	50	24.2	25.2	18
ICTE-36RLG	ICTE-36	36	2.0	42.4	_	_	1.0	65.2	23	50.6	54.3	26

- 3. Square waveform, PW = 8.3 ms, non-repetitive duty cycle.
- A transient suppressor is normally selected according to the maximum working peak reverse voltage (V_{RWM}), which should be equal to or greater than the dc or continuous peak operating voltage level.
 V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C and minimum voltage in V_{BR} is to be controlled.
 Surge current waveform per Figure 5 and derate per Figures 1 and 2.

- †The "G" suffix indicates Pb-Free package or Pb-Free packages are available.

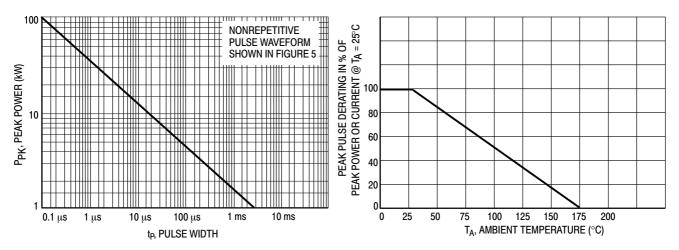


Figure 1. Pulse Rating Curve

Figure 2. Pulse Derating Curve

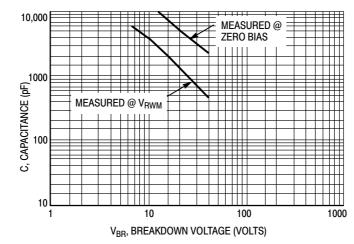


Figure 3. Capacitance versus Breakdown Voltage

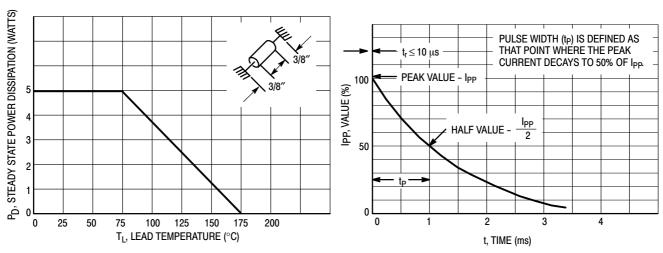
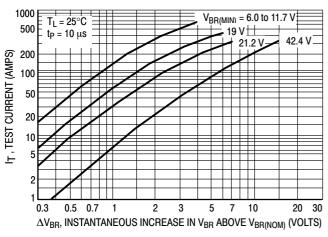


Figure 4. Steady State Power Derating

Figure 5. Pulse Waveform



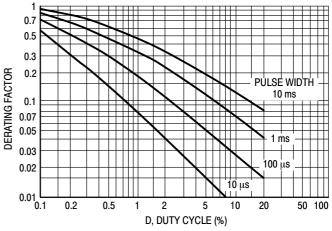


Figure 6. Dynamic Impedance

Figure 7. Typical Derating Factor for Duty Cycle

APPLICATION NOTES

RESPONSE TIME

In most applications, the transient suppressor device is placed in parallel with the equipment or component to be protected. In this situation, there is a time delay associated with the capacitance of the device and an overshoot condition associated with the inductance of the device and the inductance of the connection method. The capacitance effect is of minor importance in the parallel protection scheme because it only produces a time delay in the transition from the operating voltage to the clamp voltage as shown in Figure 8.

The inductive effects in the device are due to actual turn-on time (time required for the device to go from zero current to full current) and lead inductance. This inductive effect produces an overshoot in the voltage across the equipment or component being protected as shown in Figure 9. Minimizing this overshoot is very important in the application, since the main purpose for adding a transient suppressor is to clamp voltage spikes. These devices have excellent response time, typically in the picosecond range and negligible inductance. However, external inductive effects could produce unacceptable overshoot. Proper

circuit layout, minimum lead lengths and placing the suppressor device as close as possible to the equipment or components to be protected will minimize this overshoot.

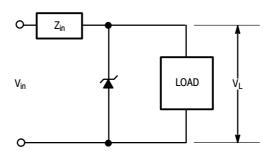
Some input impedance represented by Z_{in} is essential to prevent overstress of the protection device. This impedance should be as high as possible, without restricting the circuit operation.

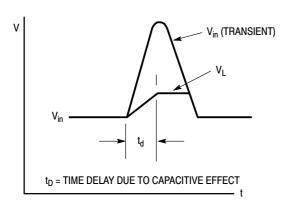
DUTY CYCLE DERATING

The data of Figure 1 applies for non-repetitive conditions and at a lead temperature of 25°C. If the duty cycle increases, the peak power must be reduced as indicated by the curves of Figure 7. Average power must be derated as the lead or ambient temperature rises above 25°C. The average power derating curve normally given on data sheets may be normalized and used for this purpose.

At first glance the derating curves of Figure 7 appear to be in error as the 10 ms pulse has a higher derating factor than the 10 μs pulse. However, when the derating factor for a given pulse of Figure 7 is multiplied by the peak power value of Figure 1 for the same pulse, the results follow the expected trend.

TYPICAL PROTECTION CIRCUIT





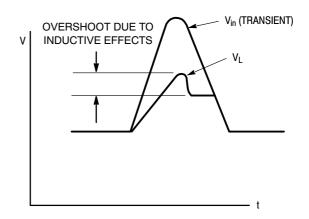
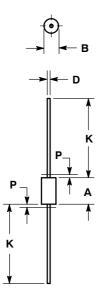


Figure 8. Figure 9.

PACKAGE DIMENSIONS

MOSORB CASE 41A-04 ISSUE D



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M. 1982.
- CONTROLLING DIMENSION: INCH.
- 3. LEAD FINISH AND DIAMETER UNCONTROLLED IN DIMENSION P.
- 4. 041A-01 THRU 041A-03 OBSOLETE, NEW STANDARD 041A-04.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.335	0.374	8.50	9.50		
В	0.189	0.209	4.80	5.30		
D	0.038	0.042	0.96	1.06		
K	1.000		25.40			
Р		0.050		1.27		

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